# Current Limit Switch, with OVP and TRCB, 28 V / 5 A Rated

# **FPF2895C**

# Description

The FPF2895C features a 28 V and 5 A rated current limit power switch, which offers Over–Current Protection (OCP), Over–Voltage Protection (OVP), and True Reverse Current Block (TRCB) to protect system. It has low On–resistance of typical 27 m $\Omega$  with WL–CSP can operate over an input voltage range of 4 V to 22 V.

The FPF2895C supports  $\pm 10\%$  of current limit accuracy, over-current range of 500 mA to 2 A and  $\pm 5\%$  of current limit accuracy, over-current range of 2 A to 5 A, flexible operations such as selectable OVP, selectable ON polarity and selectable OCP behavior, which can be optimized according to system requirements.

The FPF2895C is available in a 24-bump, 1.67 mm x 2.60 mm Wafer-Level Chip-Scale Package (WLCSP) with 0.4 mm pitch.

# Features

- 28 V / 5 A Capability
- Wide Input Voltage Range: 4 V ~ 22 V
- Ultra Low On–Resistance
  - Typ. 27 m $\Omega$  at 5 V and 25 °C
- Adjustable Current Limit with external RSET
  500 mA ~ 5 A
- Selectable OVLO with OV1 and OV2 Logic Input
  - ◆ 5.95 V ± 50 mV
  - $10 \text{ V} \pm 100 \text{ mV}$
  - ◆ 16.8 V ± 300 mV
  - 23 V ± 460 mV
- Selectable ON Polarity
- Selectable Over-Current Behavior
  - ♦ Auto-Restart Mode
  - Current Source Mode
- True Reverse Current Block
- Thermal Shutdown
- Open Drain Fault FLAGB Output
- UL60950-1 & IEC 60950-1 Certification 5 A Max Loading
- Robust ESD Capability
  - 2 kV HBM & 1 kV CDM
  - 15 kV Air Discharge & 8 kV Contact Discharge under IEC 61000-4-2

# Applications

- Laptop, Desktop Computing and Monitor
- Power Accessories



# **ON Semiconductor®**

www.onsemi.com



WLCSP24 2.6x1.67x0.612 CASE 567TQ



### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

# Table 1. ORDERING INFORMATION

Part Number	Operating Temperature Range	Top Mark	Package	Packing Method
FPF2895CUCX	−40°C − +85°C	3G	24-Ball, 0.4 mm Pitch WLCSP	Tape & Reel

# **Application Diagram**



Figure 1. Typical Application

#### **Block Diagram**



Figure 2. Functional Block Diagram

# **PIN CONFIGURATION**





#### Table 2. PIN DEFINITIONS

Name	Bump	Туре	Description
VIN	C3, D3, D4, E3, E4, F3, F4	Input/Supply	Switch Input and Device Supply
VOUT	C2, D1, D2, E1, E2, F1, F2	Output	Switch Output to Load
NC	A1	Dummy	Recommended to connect to GND
ON	A2	Input	Internal pull-down resistor of 1 M $\Omega$ is included. Active polarity is depending on POL state (Note 1)
POL	A4	Input	Enable Polarity Selection. Internal pull/up of 1 M $\Omega$ is included. HIGH (or Floating): Active LOW LOW: Active HIGH (Note 1)
FLAGB	A3	Output	Active LOW, open drain output indicates an over-current, under-voltage, over-voltage, or over-temperature state.
ISET	C1	Input	A resistor from ISET to ground set the current limit for the switch. See below selection Table 6.
OC_MODE	B2	Input	OCP behavior can be selected. Internal pull-up of 1 M $\Omega$ is included. HIGH (or Floating): Auto-restart mode during over-current condition. LOW: Current source mode during over-current condition. (Note 1)
OV1	B3	Input	Over–Voltage Selection Input 1. Internal pull–up of 1 M $\Omega$ is included and see below selection Table 7. (Note 1)
OV2	C4	Input	Over–Voltage Selection Input 2. Internal pull–up of 1 $M\Omega$ is included and see Table 7 (Note 1)
GND	B1, B4	GND	Device Ground

1. To avoid external noise influence when floating, recommend to connect these pins to a certain level.

### **Table 3. ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter			Max.	Unit
VIN, VOUT	VIN, VOUT to GND		-0.3	28.0	V
V <sub>PIN</sub>	ON, POL, OC_MODE, ISET, FLAGI	B and OVn to GND	-0.3	6.0	V
I <sub>SW</sub>	Continuous Switch Current			5.5	А
t <sub>PD</sub>	Total Power Dissipation at T <sub>A</sub> = 25°0	C		2.08	W
T <sub>STG</sub>	Storage Junction Temperature			+150	°C
TJ	Operating Junction Temperature		+150	°C	
TL	Lead Temperature (Soldering, 10 Se		+260	°C	
θ <sub>JA</sub>	Thermal Resistance, Junction-to-A		60 (Note 2)	°C/W	
ESD	Electrostatic Discharge Capability	Human Body Model, ANSI/ESDA/JEDEC JS-001	2		
		Charged Device Model, JESD22-C101	1		kV
	IEC61000-4-2 System Level	Air Discharge	15		
		Contact Discharge	8		

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.Measured using 2S2P JEDEC std. PCB.

### **Table 4. RECOMMENDED OPERATING CONDITIONS**

Symbol	nbol Parameter		Max.	Unit
V <sub>IN</sub>	Supply Voltage	4.0	22.0	V
$C_{IN/}C_{OUT}$	COUT Input and Output Capacitance			μF
T <sub>A</sub>	Ambient Operating Temperature		+85	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

Table 5. ELECTRICAL CHARACTERISTICS (Unless otherwise noted, $V_{IN}$ = 4 to 22 V, $T_A$ = -40 to 85°C; typical values are at
$V_{IN} = 5 \text{ V}, C_{IN} = C_{OUT} = 1 \ \mu\text{F}, \text{ ON} = \text{HIGH}, \text{ POL} = \text{OV1} = \text{OV2} = \text{OC}_{MODE} = \text{GND} \text{ and } T_A = 25^{\circ}\text{C}.)$

Symbol	Parameter	Conditions		Min.	Тур.	Max.	Unit
BASIC OPER	ATION				•		•
V <sub>IN</sub>	Input Voltage (Note 4)			4		22	V
I <sub>SD_IN</sub>	V <sub>IN</sub> Shutdown Current	$V_{ON}$ = OFF, $V_{IN}$ = 5.5 V, $V_{OUT}$ GND	= Short to		75	100	μΑ
			V <sub>IN</sub> = 5 V		270	330	μΑ
Ι <sub>Q</sub>	Quiescent Current	I <sub>OUT</sub> = 0 mA, V <sub>ON</sub> = ON	V <sub>IN</sub> = 12 V		300	400	
			V <sub>IN</sub> = 20 V		350	450	
			V <sub>IN</sub> = 5 V		27	39	
R <sub>ON</sub>	On Resistance	$T_A = 25^{\circ}C$ , $I_{OUT} = 1 A$	V <sub>IN</sub> = 12 V		27	39	mΩ
			V <sub>IN</sub> = 20 V		27	39	
I <sub>ON</sub>	ON Input Leakage	V <sub>ON</sub> = V <sub>IN</sub> or GND	·			10	μΑ
V <sub>IH</sub>	Logic Pin Input (ON, POL, OV1, OV2, OC_MODE) High Voltage	V <sub>IN</sub> = 3 V ~ 23 V		1.2			v
V <sub>IL</sub>	Logic Pin Input (ON, POL, OV1, OV2, OC_MODE) Low Voltage	$V_{IN} = 3 V \sim 23 V$				0.4	v
V <sub>P_LOW</sub>	FLAGB Output Logic Low Volt- age	V <sub>IN</sub> = 5 V, I <sub>SINK</sub> = 5 mA			0.1	0.2	V
I <sub>LKG</sub>	FLAGB Output High, Leakage Current	V <sub>IN</sub> = 5 V, Switch ON				1	μA
PROTECTION	S				•		•
1	Current Limit (Nete 2)	$V_{IN}$ = 5 V, $V_{OUT}$ = 4 V, $R_{SET}$ = 3.01 kΩ, $T_A$ = –40 to 85°C		1.35	1.50	1.65	
LIM	I <sub>LIM</sub> Current Limit (Note 3)	$V_{IN}$ = 5 V, $V_{OUT}$ = 4 V, $R_{SET}$ = 1.54 k $\Omega$ , $T_A$ = -40 to 85°C		2.85	3.00	3.15	
V <sub>FOLD</sub>	ILIM Foldback Trip Voltage (Note 3)	V <sub>OUT</sub> under ILIM Mode			2		V
		$V_{IN} = 5 V, V_{OUT} < V_{FOLD}, T_A = OC_MODE = HIGH$	25°C,		500		mA
IFOLD	TEIM FOIDBACK Current (Note 3)	$V_{IN} = 5 V, V_{OUT} < V_{FOLD}, T_A = OC_MODE = LOW$	25°C,		250		mA
		V <sub>IN</sub> Increasing			2.70	2.95	V
V <sub>UVLO</sub>	Under-Vollage Lockoul	V <sub>IN</sub> Decreasing			2.5		V
	UVLO Hysteresis				200		mV
			V <sub>IN</sub> Rising	22.20	23.00	23.46	
		OVI = LOVV, OV2 = LOVV	V <sub>IN</sub> Falling	22.00			- - - - -
			V <sub>IN</sub> Rising	9.80	10.00	10.10	
Ň		OV1 = LOW, OV2 = HIGH	V <sub>IN</sub> Falling	9.75			
VOVLO	Over-voltage Lockout (Note 3)		V <sub>IN</sub> Rising	16.30	16.80	17.10	
		0v1 = HIGH, 0V2 = LOW	V <sub>IN</sub> Falling	16.10			
			V <sub>IN</sub> Rising	5.85	5.95	6.00	
		OV1 = HIGH, OV2 = HIGH V <sub>IN</sub> Falling		5.80		1	
T <sub>OVP</sub>	OVP Response Time (Note 3)	$R_L$ = 100 Ω, $C_L$ = 0 μF, $V_{IN}$ > $V_{OVLO}$ to $V_{OUT}$ = 0.9 × $V_{IN}$				150	ns
V <sub>T BCB</sub>	TRCB Protection Trip Point	V <sub>OUT –</sub> V <sub>IN</sub>			25	40	mV

V <sub>R_RCB</sub>	TRCB Protection, Release Point	V <sub>IN –</sub> V <sub>OUT</sub>	25	40	mV
t <sub>RCB</sub>	TRCB Response Time (Note 3)	V <sub>IN</sub> = 5 V, V <sub>ON</sub> = HIGH/LOW	5		μs
t <sub>RCB_Release</sub>	TRCB Release Time (Note 3)	V <sub>IN</sub> = 5 V, Enabled	1		μs
toc	Over Current Response Time	V <sub>IN</sub> = 5 V, Moderate OC	20		
	(Note 3)	V <sub>IN</sub> = 5 V, Hard Short	5		μs
I <sub>SD_OUT</sub>	VOUT Shutdown Current	$V_{ON} = OFF, V_{OUT} = 5 V, V_{IN} = Short to GND$		2	μA
TSD	Thermal Shutdown (Note 3)	Shutdown Threshold	150		
		Hysteresis	20		°C
DYNAMIC BEH	AVIOR				
t <sub>DON</sub>	Delay On Time	$R_L = 100 \ \Omega \ C_L = 1 \ \mu F$	1		ms
t <sub>R</sub>	V <sub>OUT</sub> Rise Time	$R_L = 100 \ \Omega \ C_L = 1 \ \mu F$	1		ms
t <sub>ON</sub>	Turn-On Time	$R_L = 100 \ \Omega \ C_L = 1 \ \mu F$	2		ms
t <sub>DOFF</sub>	Delay Off Time	$R_L = 100 \ \Omega \ C_L = 1 \ \mu F$	10		μs
t <sub>F</sub>	V <sub>OUT</sub> Fall Time	$R_L = 100 \ \Omega \ C_L = 1 \ \mu F$	200		μs
t <sub>OFF</sub>	Turn-Off Time	$R_L = 100 \ \Omega \ C_L = 1 \ \mu F$	210		μs
t <sub>BLANK</sub>	Over-Current Blanking Time (Note 3)	OC_MODE = HIGH	5		ms
t <sub>RSTRT</sub>	Auto-Restart Time (Note 3)	OC_MODE = HIGH	200		ms

Table 5. ELECTRICAL CHARACTERISTICS (Unless otherwise noted, V <sub>IN</sub> = 4 to 22 V, T <sub>A</sub> = -40 to 85°C; typical values are at
$V_{IN} = 5 V$ , $C_{IN} = C_{OUT} = 1 \mu F$ , $ON = HIGH$ , $POL = OV1 = OV2 = OC_MODE = GND$ and $T_A = 25^{\circ}C$ .)

3. Guaranteed by characterization and design, not production test.

**Over-Current Qualification** 

FLAGB De-bounce Time

Time (Note 3)

(Note 3)

4. To avoid output voltage is coupled to high during cold start, the slew rate of Vin should be less than 10 mV/µs

OC\_MODE = LOW

Restart-up during or after OC

Restart-up during or after UVLO

Restart-up during or after Thermal shutdown

#### **Setting Current Limit**

t<sub>QUAL</sub>

t<sub>DEB</sub>

FPF2895C current limit is set with an external resistor connected between  $I_{SET}$  and GND. This resistor is selected using the following equation:

$$R_{SET}(k\Omega) = \left(\frac{4674.89}{I_{SET}MA}\right)^{1/1.0326}$$
 (eq. 1)

Resistor tolerance of 1% or less is recommended. 5% tolerance can be achieved only when ILIM is set to larger than 2 A.

5

3

15

1

ms

ms

#### Table 6. ILIM VS. RSET LOOK-UP TABLE

	ILIM [mA]				
RSET [kΩ]	Min.	Тур.	Max.		
8.75	450	500	550		
7.35	540	600	660		
6.30	630	700	770		
5.55	720	800	880		
4.95	810	900	990		
4.45	900	1000	1100		
4.06	990	1100	1210		
3.73	1080	1200	1320		

### Table 6. ILIM VS. RSET LOOK-UP TABLE

	ILIM [mA]				
RSET [kΩ]	Min.	Тур.	Max.		
3.45	1170	1300	1430		
3.21	1260	1400	1540		
3.01	1350	1500	1650		
2.82	1440	1600	1760		
2.66	1530	1700	1870		
2.52	1620	1800	1980		
2.39	1710	1900	2090		
2.28	1900	2000	2100		
2.17	1995	2100	2205		
2.07	2090	2200	2310		
1.99	2185	2300	2415		
1.91	2280	2400	2520		
1.83	2375	2500	2625		
1.77	2470	2600	2730		
1.70	2565	2700	2835		
1.64	2660	2800	2940		
1.59	2755	2900	3045		
1.54	2850	3000	3150		
1.49	2945	3100	3255		
1.44	3040	3200	3360		
1.40	3135	3300	3465		
1.36	3230	3400	3570		
1.32	3325	3500	3675		
1.29	3420	3600	3780		
1.25	3515	3700	3885		
1.22	3610	3800	3990		
1.19	3705	3900	4095		
1.16	3800	4000	4200		
1.14	3895	4100	4305		
1.11	3990	4200	4410		
1.08	4085	4300	4515		
1.06	4180	4400	4620		
1.04 (Note 5)	4275	4500	4725		
1.02	4370	4600	4830		
0.99	4465	4700	4935		
0.97	4560	4800	5040		
0.96	4655	4900	5145		
0.94	4750	5000	5250 (Note 6)		

5. Passed UL&CB certification with max. 5 A output current.
 6. 6 A absolute limit current value. See Figure 9. for protection timing diagram.

### Table 7. OVLO LEVEL SELECTION

OV1	OV2	OVLO
LOW	LOW	23 V ± 460 mV
LOW	HIGH (Floating)	10 V ± 100 mV
HIGH (Floating)	LOW	$16.3\pm V~300~mV$
HIGH (Floating)	HIGH (Floating)	$5.95\pm$ V 50 mV

# Table 8. DEVICE ENABLE POLARITY SELECTION

POL	ON	Device State	ON Polarity
LOW	LOW (Floating)	OFF	
LOW	HIGH	ON	Active FIGH
HIGH (Floating)	LOW (Floating)	ON	
HIGH (Floating)	HIGH	OFF	Active LOW

# TIMING DIAGRAMS























Figure 9. VOUT Hard Short to GND (OC\_MODE=HIGH & FLAGB Is Pulled Up With an External VIO)

# **PRODUCT-SPECIFIC DIMENSIONS**

D	E	Х	Y
2600 $\mu\text{m}\pm$ 30 $\mu\text{m}$	1670 $\mu$ m $\pm$ 30 $\mu$ m	235 $\mu m \pm$ 18 $\mu m$	300 $\mu m \pm$ 18 $\mu m$





DOCUMENT NUMBER:	98AON13331G	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	WLCSP24 2.6x1.67x0.612		PAGE 1 OF 1	
ON Semiconductor and ()) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others				

© Semiconductor Components Industries, LLC, 2019

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor date sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use a a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor houteds for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

#### TECHNICAL SUPPORT

ON Semiconductor Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800–282–9855 Toll Free USA/Canada Phone: 011 421 33 790 2910 Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative